PHEMT GaAs IC SPDT Switch DC-2.5 GHz

0.0256 (0.65 mm)

BSC

0.049 (1.25 mm)

± 0.004 (0.10 mm)

0.009 (0.23 mm) REF

- 0.010 (0.25 mm)

± 0.006 (0.15 mm)

0.008 (0.20 mm)

± 0.004 (0.10 mm)

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AS183-92

Features

- P_{1 dB} +30 dBm Typical @ +3 V
- IP3 43 dBm Typical @ +3 V
- Low Insertion Loss (0.3 dB @ 0.9 GHz)
- Low DC Power Consumption
- Miniature SC-70 6 Lead Plastic Package

Description

The AS183-92 is an IC FET SPDT switch in a very small SC-70 6 lead plastic package. The AS183-92 features low insertion loss and positive voltage operation with very low DC power consumption. This switch is suitable for handset applications.

Electrical Specifications at 25°C (0, +3 V)

Parameter ¹	Frequency ²	Min.	Тур.	Max.	Unit
Insertion Loss ³	DC-1.0 GHz		0.30	0.4	dB
	DC–2.0 GHz		0.30	0.4	dB
	DC-2.5 GHz		0.55	0.6	dB
Isolation	DC-1.0 GHz	18	20		dB
	DC–2.0 GHz	12	14		dB
	DC-2.5 GHz	11	13		dB
VSWR ⁴	DC-2.5 GHz		1.2:1	1.6:1	

SC-70 6 Lead

0.079 (2.00 mm)

± 0.008 (0.20 mm)

PIN 1 INDICATOR

0.035 (0.90 mm)

0.002 (0.005 mm)

± 0.004 (0.10 mm)

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± 0.002 (0.005 mm) 0.037 (0.95 mm)

0.0055

(0.14 mm)

± 0.0015 (0.04 mm)

± 0.006 (0.15 mm)

0.087 (2.20 mm)

± 0.008 (0.20 mm)

Operating Characteristics at 25°C (0, +3 V)

Parameter	Condition	Frequency	Min.	Тур.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF)			10		ns
	On, Off (50% CTL to 90/10% RF)			20		ns
	Video Feedthru			25		mV
Input Power for 1 dB Compression	0/+3 V	0.5–2.5 GHz		+30		dBm
	0/+5 V	0.5–2.5 GHz		+34		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +15 dBm					
	0/+3 V	0.5–2.5 GHz		+43		dBm
	0/+5 V	0.5–2.5 GHz		+50		dBm
Control Voltages	V _{Low} = 0 to 0.2 V @ 20 μA Max.					
V _{High} = +3 V @ 100 μA Max. to +5 V @ 200 μA Max.						

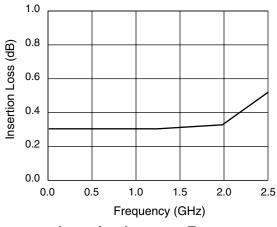
1. All measurements made in a 50 Ω system, unless otherwise specified.

2. DC = 300 kHz.

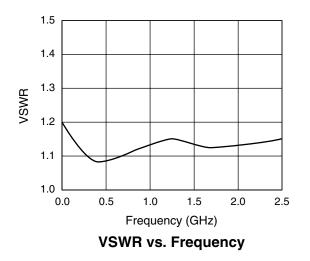
Insertion loss changes by 0.003 dB/°C.
Insertion loss state.

5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

Typical Performance Data (0, +3 V)



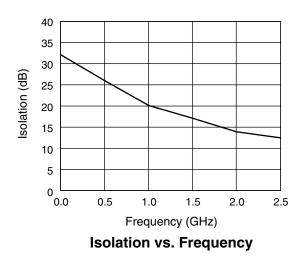
Insertion Loss vs. Frequency



Truth Table

V ₁	V ₂	$J_1 - J_2$	$J_1 - J_3$
0	V _{High}	Isolation	Insertion Loss
V _{High}	0	Insertion Loss	Isolation

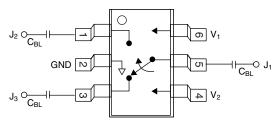
 $V_{\text{High}} = +3 \text{ to } +5 \text{ V.}$



Absolute Maximum Ratings

Characteristic	Value
RF Input Power	6 W > 500 MHz 0/+7 V Control
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Θ _{JC}	25°C/W

Pin Out



DC blocking capacitors (C_{BL}) must be supplied externally for positive voltage operation. C_{BL} = 100 pF for operation >500 MHz.